

October 2014

MOC205M, MOC206M, MOC207M, MOC211M, MOC212M, MOC213M, MOC216M, MOC217M 8-pin SOIC Single-Channel Phototransistor Output Optocoupler

Features

- Closely Matched Current Transfer Ratios
- Minimum BV_{CEO} of 70 V Guaranteed
 - MOC205M, MOC206M, MOC207M
- Minimum BV_{CFO} of 30 V Guaranteed
 - MOC211M, MOC212M, MOC213M, MOC216M, MOC217M
- Low LED Input Current Required for Easier Logic Interfacing
 - MOC216M, MOC217M
- Convenient Plastic SOIC-8 Surface Mountable Package Style, with 0.050" Lead Spacing
- Safety and Regulatory Approvals:
 - UL1577, 2,500 VAC_{RMS} for 1 Minute
 - DIN-EN/IEC60747-5-5, 565 V Peak Working Insulation Voltage

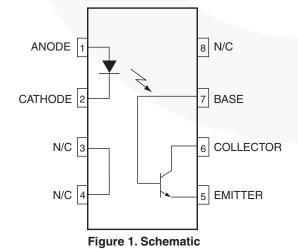
Applications

- Feedback Control Circuits
- Interfacing and Coupling Systems of Different Potentials and Impedances
- General Purpose Switching Circuits
- Monitor and Detection Circuits

Description

These devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon phototransistor detector, in a surface mountable, small outline, plastic package. They are ideally suited for high-density applications, and eliminate the need for through-the-board mounting.

Schematic



Package Outline

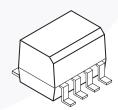


Figure 2. Package Outline

Safety and Insulation Ratings

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Parameter	Characteristics	
Installation Classifications per DIN VDE	< 150 V _{RMS}	I–IV
0110/1.89 Table 1, For Rated Mains Voltage	< 300 V _{RMS}	I–III
Climatic Classification		55/100/21
Pollution Degree (DIN VDE 0110/1.89)		2
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit
V	Input-to-Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test with $t_m = 10 \text{ s}$, Partial Discharge < 5 pC	904	V _{peak}
V _{PR}	Input-to-Output Test Voltage, Method B, $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with $t_m = 1$ s, Partial Discharge < 5 pC	1060	V _{peak}
V _{IORM}	Maximum Working Insulation Voltage	565	V _{peak}
V _{IOTM}	Highest Allowable Over-Voltage	4000	V _{peak}
	External Creepage	≥ 4	mm
	External Clearance	≥ 4	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥ 0.4	mm
T _S	Case Temperature ⁽¹⁾	150	°C
I _{S,INPUT}	Input Current ⁽¹⁾	200	mA
P _{S,OUTPUT}	Output Power ⁽¹⁾	300	mW
R _{IO}	Insulation Resistance at T _S , V _{IO} = 500 V ⁽¹⁾	> 10 ⁹	Ω

Note:

1. Safety limit values – maximum values allowed in the event of a failure.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A = 25^{\circ}C$ unless otherwise specified.

Symbol	Rating	Value	Unit
TOTAL DEVI	CE		
T _{STG}	Storage Temperature	-40 to +125	°C
T _A	Ambient Operating Temperature	-40 to +100	°C
TJ	Junction Temperature	-40 to +125	°C
T _{SOL}	Lead Solder Temperature	260 for 10 seconds	°C
	Total Device Power Dissipation @ T _A = 25°C	240	mW
P_{D}	Derate above 25°C	2.94	mW/°C
EMITTER			
I _F	Continuous Forward Current	60	mA
I _F (pk)	Forward Current – Peak (PW = 100 µs, 120 pps)	1.0	Α
V_{R}	Reverse Voltage	6.0	V
Б	LED Power Dissipation @ T _A = 25°C	90	mW
P_{D}	Derate above 25°C	0.8	mW/°C
DETECTOR			
I _C	Continuous Collector Current	150	mA
V _{CEO}	Collector-Emitter Voltage	30	V
V _{ECO}	Emitter-Collector Voltage	7	V
Ъ	Detector Power Dissipation @ T _A = 25°C	150	mW
P_{D}	Derate above 25°C	1.76	mW/°C

Electrical Characteristics

 $T_A = 25$ °C unless otherwise specified.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
EMITTER					II	
	Input Forward Voltage					
V_{F}	MOC216M, MOC217M	$I_F = 1 \text{ mA}$		1.07	1.3	V
٧F	MOC205M, MOC206M, MOC207M MOC211M, MOC212M, MOC213M	I _F = 10 mA		1.15	1.5	٧
I _R	Reverse Leakage Current	V _R = 6 V		0.001	100	μΑ
C _{IN}	Input Capacitance			18		pF
DETECTO	DR .		•	-		
I _{CEO1}		$V_{CE} = 10 \text{ V}, T_{A} = 25^{\circ}\text{C}$		1.0	50	nA
I _{CEO2}	Collector-Emitter Dark Current	V _{CE} = 10 V, T _A = 100°C		1.0		μΑ
	Collector-Emitter Breakdown Voltage					
BV _{CEO}	MOC205M, MOC206M, MOC207M	$I_{\rm C} = 100 \ \mu {\rm A}$	70	100		V
D A CEO	MOC211M, MOC212M, MOC213M, MOC216M, MOC217M	I _C = 100 μA	30	100		V
BV _{CBO}	Collector-Base Breakdown Voltage	I _C = 10 μA	70	120		V
BV _{ECO}	Emitter-Collector Breakdown Voltage	I _E = 100 μA	7	10		V
C _{CE}	Collector-Emitter Capacitance	$f = 1.0 \text{ MHz}, V_{CE} = 0$		7		pF
COUPLE	D .					
	Collector-Output Current					
	MOC205M	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	40		80	%
	MOC206M	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	63		125	%
	MOC207M	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	100		200	%
CTR	MOC211M	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	20			%
	MOC212M	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	50			%
	MOC213M	I _F = 10 mA, V _{CE} = 10 V	100			%
	MOC216M	I _F = 1 mA, V _{CE} = 5 V	50			%
	MOC217M	I _F = 1 mA, V _{CE} = 5 V	100			%
	Collector-Emitter Saturation Voltage					
V _{CE(SAT)}	MOC205M, MOC206M, MOC207M MOC211M, MOC212M, MOC213M	I _C = 2 mA, I _F = 10 mA			0.4	V
	MOC216M, MOC217M	$I_C = 100 \mu A, I_F = 1 mA$			0.4	V
t _{on}	Turn-On Time	$I_C = 2 \text{ mA}, V_{CC} = 10 \text{ V},$ $R_L = 100 \Omega \text{ (Figure 12)}$		7.5		μs
t _{off}	Turn-Off Time	I_C = 2 mA, V_{CC} = 10 V, R_L = 100 Ω (Figure 12)		5.7		μs
t _r	Rise Time	I_C = 2 mA, V_{CC} = 10 V, R_L = 100 Ω (Figure 12)		3.2		μs
t _f	Fall Time	$I_C = 2 \text{ mA}, V_{CC} = 10 \text{ V},$ $R_L = 100 \Omega \text{ (Figure 12)}$		4.7		μs

Isolation Characteristics

Symbol	Characteristic Test Conditions		Min.	Тур.	Max.	Units
V _{ISO}	Input-Output Isolation Voltage	t = 1 Minute	2500			VAC _{RMS}
C _{ISO}	Isolation Capacitance	V _{I-O} = 0 V, f = 1 MHz		0.2		pF
R _{ISO}	Isolation Resistance	$V_{I-O} = \pm 500 \text{ VDC}, T_A = 25^{\circ}\text{C}$	10 ¹¹			Ω

Typical Performance Curves

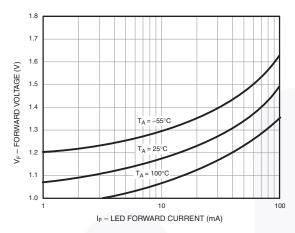


Figure 3. LED Forward Voltage vs. Forward Current

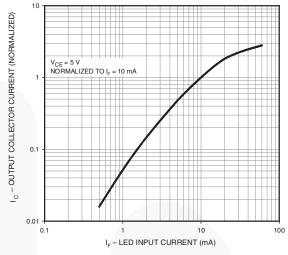


Figure 4. Output Curent vs. Input Current

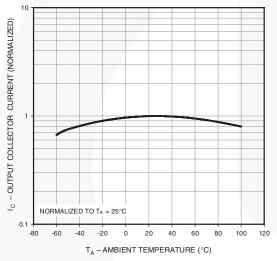


Figure 5. Output Current vs. Ambient Temperature

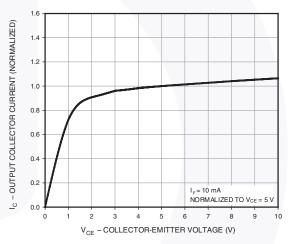


Figure 6. Output Current vs. Collector-Emitter Voltage

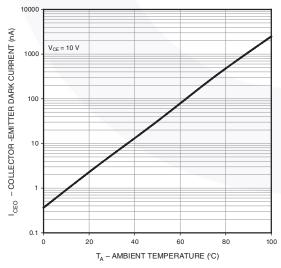


Figure 7. Dark Current vs. Ambient Temperature

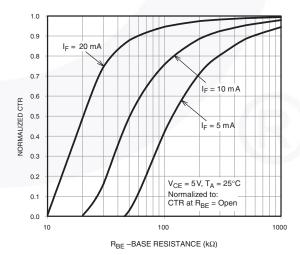


Figure 8. CTR vs. RBE (Unsaturated)

Typical Performance Curves (Continued)

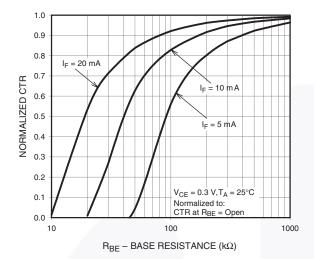


Figure 9. CTR vs. RBE (Saturated)

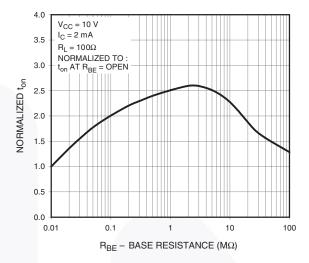


Figure 10. Normalized ton vs. RBE

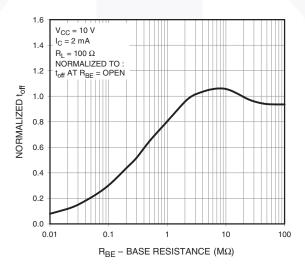


Figure 11. Normalized toff vs. RBE

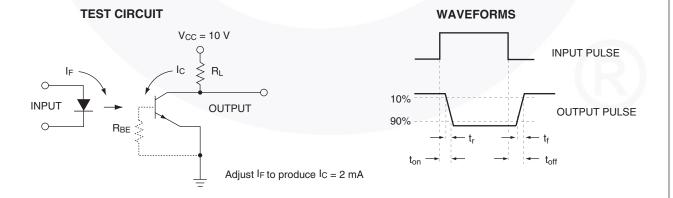


Figure 12. Switching Time Test Circuit and Waveforms

Reflow Profile

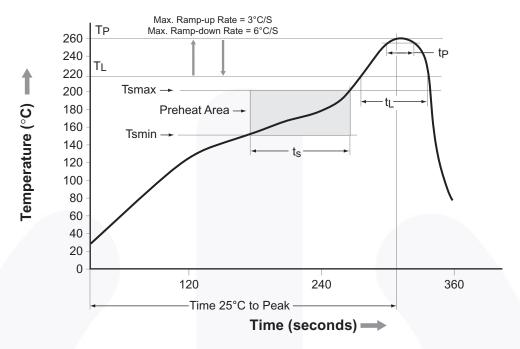


Figure 13. Reflow Profile

Profile Freature	Pb-Free Assembly Profile			
Temperature Minimum (Tsmin)	150°C			
Temperature Maximum (Tsmax)	200°C			
Time (t _S) from (Tsmin to Tsmax)	60-120 seconds			
Ramp-up Rate (t _L to t _P)	3°C/second maximum			
Liquidous Temperature (T _L)	217°C			
Time (t _L) Maintained Above (T _L)	60-150 seconds			
Peak Body Package Temperature	260°C +0°C / -5°C			
Time (t _P) within 5°C of 260°C	30 seconds			
Ramp-down Rate (T _P to T _L)	6°C/second maximum			
Time 25°C to Peak Temperature	8 minutes maximum			

Ordering Information

Part Number	Package	Packing Method
MOC205M	Small Outline 8-Pin	Tube (100 Units)
MOC205R2M	Small Outline 8-Pin	Tape and Reel (1000 Units)
MOC205VM	Small Outline 8-Pin, DIN EN/IEC60747-5-5 Option	Tube (100 Units)
MOC205R2VM	Small Outline 8-Pin, DIN EN/IEC60747-5-5 Option	Tape and Reel (1000 Units)

Note:

2. The product orderable part number system listed in this table also applies to the MOC20XM and MOC21XM products.

Marking Information

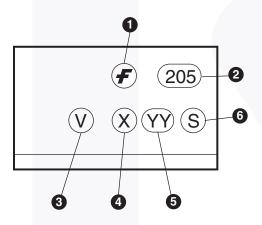
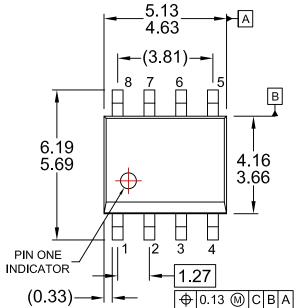


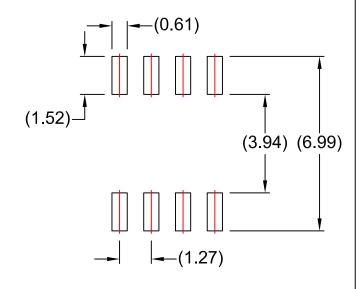
Figure 14. Top MarkTop Mark

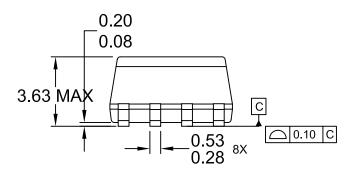
Table 1. Top Mark Definitions

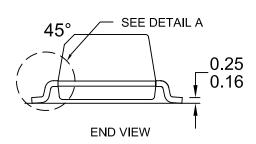
1	Fairchild Logo
2	Device Number
3	DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option)
4	One-Digit Year Code, e.g., "4"
5	Digit Work Week, Ranging from "01" to "53"
6	Assembly Package Code

	REVISIONS						
	Ltr	Description	Date	DRAWN/SITE			
	0	RELEASED PËR ECN K-11989	03-22-99	SUBRA			
	1	UPDATE TABLE PER ECN K-12528	05-02-00	R.RASAMMAL			
I	2	UPDATE FSC LOGO PER ECN K-13836	01-10-04	JAYASELAN			
	3	FULL UPDATE OF ESP-3989-00 TO FSC MKT 0001 REISSUE ESP-3989-00 AS MKT-M08E	16-6-2008	H.ALLEN/FSME			
	4	DELETED STYLE 1,2,3,4,GAGE PLANE & SEATING PLANE	18-8-2008	WEE LING			

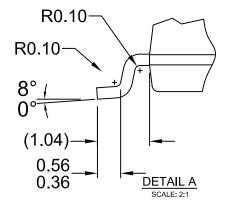








LAND PATTERN RECOMMENDATION



NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS.
- D) LANDPATTERN STANDARD: SOIC127P600X175-8M.
- E) DRAWING FILENAME: M08EPREV4

APPR	ROVALS	DATE	FAIRC	· — —			
DRAWN	I.ALLEN	16 JUN 08	SEMICON				
DFTG. CHK.							
ENGR. CHK.			8LD,SOIC, .150" BODY, OPTO,				
			WHITE COPLANAR				
PROJECTION		SCALE	SIZE	DRAWING NUMBER		REV	
		N/A		MKT-N	/108E	4	
)			DO NOT S	SCALE	DRAWING	SHEET 1 of	1





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PRODUCT STATUS DEFINITIONS

Definition of Torms

Definition of Terms					
Datasheet Identification	Product Status	Definition			
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.			
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.			
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.			
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.			

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